

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1	"5668379".pn.	USPAT	OR	OFF	2004/08/16 09:17
S3	2	(pixel near10 (direct adj contact) near10 substrate) and "349"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/08/16 09:43
S4	12	(pixel near10 (direct adj contact) near10 substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/08/16 10:01
S5	869	(pixel near10 contact near10 substrate) and (liquid adj crystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/08/16 10:17
S6	441	(pixel near10 contact near10 substrate) and (liquid adj crystal)and "349"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/08/16 10:19
S7	174	(pixel near10 contact near10 substrate) and (liquid adj crystal)and 349/43	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/08/16 10:20
S8	1655	349/139	USPAT; JPO	OR	OFF	2003/10/03 14:56
S9	1048	349/138	USPAT; JPO	OR	OFF	2002/07/30 09:30
S10	218	349/147	USPAT; JPO	OR	OFF	2002/07/30 09:30
S11	902	349/113	USPAT; JPO	OR	OFF	2002/07/30 09:30
S12	137	349/47	USPAT; JPO	OR	OFF	2002/07/30 09:31
S13	4950	((contact adj hole) with silicon)	USPAT; JPO	OR	OFF	2002/07/30 09:34
S14	100	((contact adj hole) with silicon) and "349"/\$.ccls.	USPAT; JPO	OR	OFF	2004/03/31 15:55
S15	317	((contact adj hole) with silicon) and ("349"/\$.ccls or (liquid adj crystal))	USPAT; JPO	OR	OFF	2002/07/30 09:35
S16	239	((contact adj hole) with silicon) and ("349"/\$.ccls or (liquid adj crystal))and expos\$4	USPAT; JPO	OR	OFF	2002/07/30 09:37

S17	234	((contact adj hole) with silicon) and ("349"/\$.ccls or (liquid adj crystal))and expos\$4 and (passivation or insulat\$4)	USPAT; JPO	OR	OFF	2002/09/30 17:05
S18	31	((contact adj hole) with silicon) and ("349"/\$.ccls or (liquid adj crystal))and expos\$4 and (passivation or insulat\$4) and 349/139	USPAT; JPO	OR	OFF	2003/10/03 14:57
S19	59	349/139 and 349/113	USPAT; JPO	OR	OFF	2002/07/30 17:56
S20	63	349/138 and 349/113	USPAT; JPO	OR	OFF	2002/07/30 18:00
S21	24	349/147 and 349/113	USPAT; JPO	OR	OFF	2002/07/30 18:02
S22	9	349/47 and 349/113	USPAT; JPO	OR	OFF	2002/07/30 18:03
S23	636	((contact adj hole) and silicon) and "349"/\$.ccls.	USPAT; JPO	OR	OFF	2002/09/30 09:04
S24	631	((contact adj hole) and silicon) and "349"/\$.ccls. and insulat\$4	USPAT; JPO	OR	OFF	2002/09/30 09:04
S25	162	((contact adj hole) same silicon) and "349"/\$.ccls. and (insulat\$4 same expos\$4)	USPAT; JPO	OR	OFF	2003/01/21 08:50
S26	188	349/139 and(contact adj hole)	USPAT; JPO	OR	OFF	2002/09/30 17:07
S27	139	349/139 and((contact adj hole) same (pixel or pad))	USPAT; JPO	OR	OFF	2003/01/21 08:47
S28	9	"6163356".pn. or "6190934".pn. or "5920083".pn. or "6300152".pn. or "6188461".pn. or "6078366".pn. or "5784131".pn. or "6310669".pn. or "6424399".pn.	USPAT	OR	OFF	2003/01/20 17:19
S29	1	"6344884".pn.	USPAT	OR	OFF	2003/01/20 17:19
S30	174	((contact adj hole) same pad) and "349"/\$.ccls. and expos\$4	US-PGPUB; USPAT; JPO	OR	ON	2003/01/21 08:58
S31	224	349/139 and((contact adj hole) same (pixel or pad))	US-PGPUB; USPAT; JPO	OR	ON	2003/01/21 10:08
S32	3	"5235443".pn. or "5295009".pn. or "5309265".pn.	USPAT; JPO	OR	OFF	2003/01/22 10:34
S33	773	438/30	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/03/07 13:59

S34	348	438/30 and (contact adj hole)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/03/07 14:05
S35	114	Qi.xa.	USPAT	OR	OFF	2003/04/14 16:56
S36	5386	sung.in.	US-PGPUB; USPAT	OR	ON	2003/04/14 16:57
S37	396	sung.in. and (liquid adj crystal)	US-PGPUB; USPAT	OR	ON	2003/04/14 16:57
S38	105	sung.in. and (liquid adj crystal)and (contact adj hole)	US-PGPUB; USPAT	OR	ON	2003/04/14 17:47
S39	4656	(liquid adj crystal)and (contact adj hole)	US-PGPUB; USPAT	OR	ON	2004/02/09 12:55
S40	466	349/152	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/10/03 14:57
S41	13	((contact adj hole) with silicon) and ("349"/\$.ccls or (liquid adj crystal))and expos\$4 and (passivation or insulat\$4) and 349/152	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/10/03 14:57
S42	1	"20010030718".pn.	US-PGPUB; USPAT	OR	OFF	2004/02/09 10:05
S43	23	(liquid adj crystal)and (contact adj hole)and (gate adj pad adj electrode)	US-PGPUB; USPAT; JPO	OR	ON	2004/03/31 13:37
S44	24	(liquid adj crystal)and (contact adj hole)and (gate adj pad adj electrode)	US-PGPUB; USPAT; JPO	OR	ON	2004/03/31 13:37
S45	165	((gate adj pad) with insulat\$4) and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	OFF	2004/03/31 15:55
S46	25841	pixel near10 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/08/13 16:52
S47	5890	(pixel near10 substrate) and "349"/\$. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/08/13 16:53
S48	442	(pixel near10 contact near10 substrate) and "349"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/08/16 09:40